

CAT4109

3-Channel Constant-Current RGB LED Driver with Individual PWM Dimming

Description

The CAT4109 is a 3-channel constant-current LED driver, requiring no inductor. LED channel currents up to 175 mA are programmed independently via separate external resistors. Low output voltage operation of 0.4 V at 175 mA allows for more power efficient designs across wider supply voltage range. The three LED pins are compatible with high voltage up to 25 V supporting applications with long strings of LEDs.

Three independent control inputs PWM1, PWM2, PWM3, control respectively LED1, LED2, LED3 channels. The device also includes an output enable (OE) control pin to disable all three channels independently of the PWMx input states.

Thermal shutdown protection is incorporated in the device to disable the LED outputs whenever the die temperature exceeds 150°C.

The device is available in a 16-lead SOIC package.

Features

- 3 Independent Current Sinks up to 175 mA rated 25 V
- LED Current Set by External Low Power Control Resistors
- Individual PWM Control per Channel
- Low Dropout Current Source (0.4 V at 175 mA)
- Output Enable Input for Dimming
- “Zero” Current Shutdown Mode
- 3 V to 5.5 V Logic Supply
- Thermal Shutdown Protection
- 16-lead SOIC Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

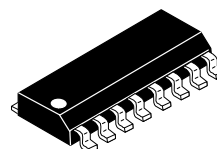
Application

- Multi-color LED, Architectural Lighting
- LED Signs and Displays
- LCD Backlight



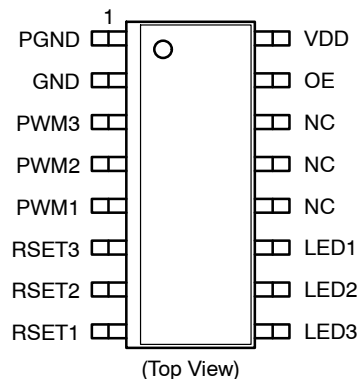
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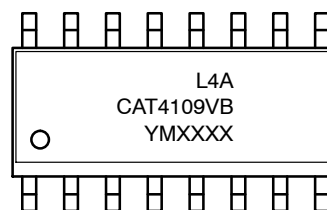


SOIC-16
V SUFFIX
CASE 751BG

PIN CONNECTIONS



MARKING DIAGRAM



L = Assembly Location
4 = Lead Finish – NiPdAu
A = Product Revision (Fixed as “A”)
CAT4109V = Device Code
B = Leave Blank
Y = Production Year (Last Digit)
M = Production Month (1–9, A, B, C)
XXXX = Last Four Digits of Assembly Lot Number

ORDERING INFORMATION

| Device | Package | Shipping |
|--------------------------|----------------------|-----------------------|
| CAT4109V-GT2 (Note 1) | SOIC-16 (Pb-Free) | 2,000/ Tape & Reel |

1. Lead Finish NiPdAu

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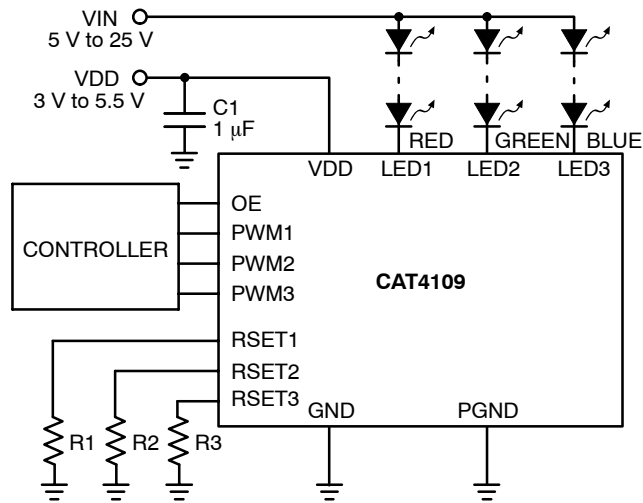


Figure 1. Typical Application Circuit

Table 1. ABSOLUTE MAXIMUM RATINGS

| Parameter | Rating | Units |
|--|---------------|-------|
| VDD Voltage | 6 | V |
| Input Voltage Range (OE, PWM1, PWM2, PWM3) | -0.3 V to 6 V | V |
| LED1, LED2, LED3 Voltage | 25 | V |
| DC Output Current on LED1 to LED3 | 200 | mA |
| Storage Temperature Range | -55 to +160 | °C |
| Junction Temperature Range | -40 to +150 | °C |
| Lead Soldering Temperature (10 sec.) | 300 | °C |
| ESD Rating on All Pins: Human Body Model Machine Model | 2000 200 | V |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 2. RECOMMENDED OPERATING CONDITIONS

| Parameter | Range | Units |
|--|------------------|-------|
| VDD | 3.0 to 5.5 | V |
| Voltage applied to LED1 to LED3, outputs off | up to 25 | V |
| Voltage applied to LED1 to LED3, outputs on | up to 6 (Note 2) | V |
| Output Current on LED1 to LED3 | 2 to 175 | mA |
| Ambient Temperature Range | -40 to +85 | °C |

2. Keeping LEDx pin voltage below 6 V in operation is recommended to minimize thermal dissipation in the package.

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Table 3. ELECTRICAL OPERATING CHARACTERISTICS (Min and Max values are over recommended operating conditions unless specified otherwise. Typical values are at $V_{DD} = 5.0\text{ V}$, $T_{AMB} = 25^{\circ}\text{C}$.)

| Symbol | Name | Conditions | Min | Typ | Max | Units |
|--------------------------------|---|--|---------------------|-----|---------------------|--------------------|
| DC CHARACTERISTICS | | | | | | |
| I_{DD1} | Supply Current Outputs Off | $V_{LED} = 5\text{ V}$, $R_{SET} = 24.9\text{ k}\Omega$ | | 2 | 5 | mA |
| I_{DD2} | Supply Current Outputs Off | $V_{LED} = 5\text{ V}$, $R_{SET} = 5.23\text{ k}\Omega$ | | 4 | 10 | mA |
| I_{DD3} | Supply Current Outputs On | $V_{LED} = 0.5\text{ V}$, $R_{SET} = 24.9\text{ k}\Omega$ | | 2 | 5 | mA |
| I_{DD4} | Supply Current Outputs On | $V_{LED} = 0.5\text{ V}$, $R_{SET} = 5.23\text{ k}\Omega$ | | 4 | 10 | mA |
| I_{SHDN} | Shutdown Current | $V_{OE} = 0\text{ V}$ | | | 1 | μA |
| I_{LKG} | LED Output Leakage | $V_{LED} = 5\text{ V}$, Outputs Off | -1 | | 1 | μA |
| R_{OE} | OE Pull-down Resistance | | 140 | 190 | 250 | $\text{k}\Omega$ |
| V_{OE_IH} V_{OE_IL} | OE Logic High Level OE Logic Low Level | | 1.3 | | 0.4 | V |
| V_{PWM_IH} V_{PWM_IL} | PWMx Logic High Level PWMx Logic Low Level | | $0.7 \times V_{DD}$ | | $0.3 \times V_{DD}$ | V |
| I_{IL} | Logic Input Leakage Current (PWMx) | $V_{PWMx} = V_{DD}$ or GND | -5 | 0 | 5 | μA |
| V_{RSETx} | RSETx Regulated Voltage | | 1.17 | 1.2 | 1.23 | V |
| T_{SD} | Thermal Shutdown | | | 150 | | $^{\circ}\text{C}$ |
| T_{HYS} | Thermal Hysteresis | | | 20 | | $^{\circ}\text{C}$ |
| I_{LED}/I_{RSET} | RSET to LED Current Gain Ratio | 100 mA LED Current | | 400 | | |
| V_{UVLO} | Undervoltage Lockout (UVLO) Threshold | | | 1.8 | | V |

Table 4. RECOMMENDED TIMING (Min and Max values are over recommended operating conditions unless specified otherwise. Typical values are at $V_{DD} = 5.0\text{ V}$, $T_{AMB} = 25^{\circ}\text{C}$.)

| Symbol | Name | Conditions | Min | Typ | Max | Units |
|--------------|--|---------------------------|-----|-----|-----|---------------|
| t_{PS} | Turn-On time, OE rising to I_{LED} from Shutdown | $I_{LED} = 100\text{ mA}$ | | 1.4 | | μs |
| t_{P1} | Turn-On time, OE or PWMx rising to I_{LED} | $I_{LED} = 100\text{ mA}$ | | 600 | | ns |
| t_{P2} | Turn-Off time, OE or PWMx falling to I_{LED} | $I_{LED} = 100\text{ mA}$ | | 300 | | ns |
| t_R | LED rise time | $I_{LED} = 100\text{ mA}$ | | 300 | | ns |
| t_F | LED fall time | $I_{LED} = 100\text{ mA}$ | | 300 | | ns |
| t_{LO} | OE low time | | 1 | | | μs |
| t_{HI} | OE high time | | 5 | | | μs |
| t_{PWRDWN} | OE low time to shutdown delay | | | 4 | 8 | ms |

TYPICAL PERFORMANCE CHARACTERISTICS

($V_{IN} = 5\text{ V}$, $V_{DD} = 5\text{ V}$, $C1 = 1\ \mu\text{F}$, $T_{AMB} = 25^\circ\text{C}$ unless otherwise specified.)

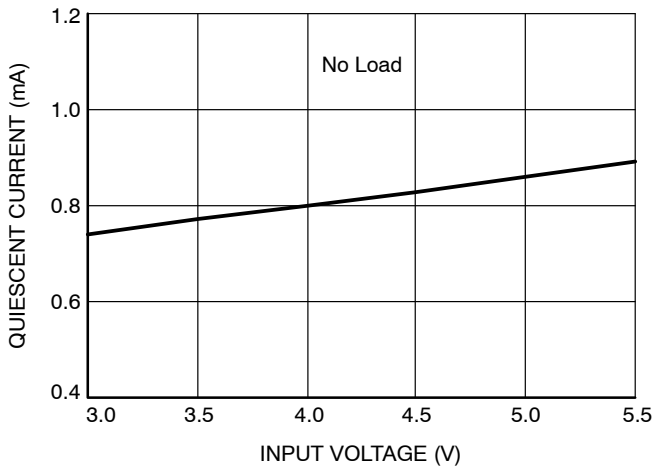


Figure 3. Quiescent Current vs. Input Voltage
($I_{LED} = 0\text{ mA}$)

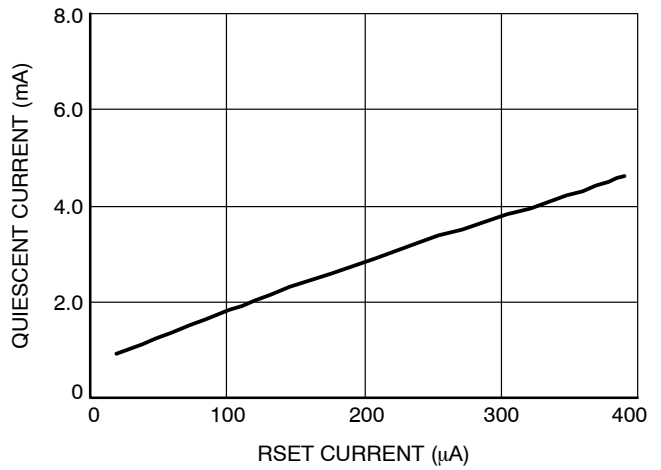


Figure 4. Quiescent Current vs. RSET Current

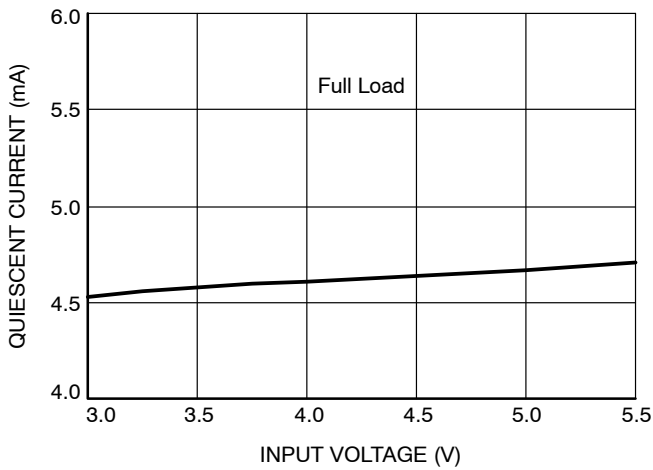


Figure 5. Quiescent Current vs. Input Voltage
($I_{LED} = 175\text{ mA}$)

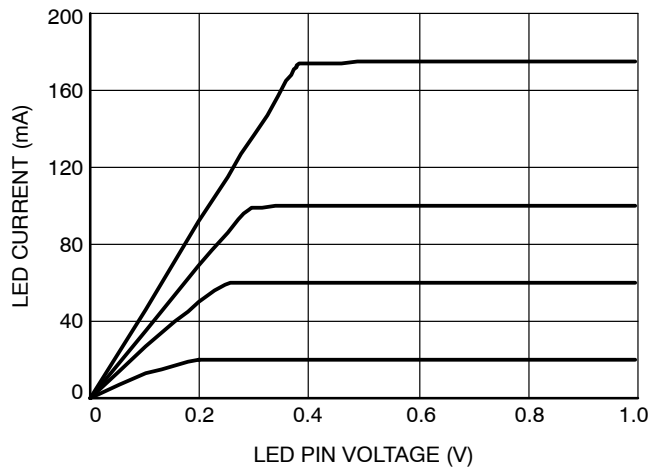


Figure 6. LED Current vs. LED Pin Voltage

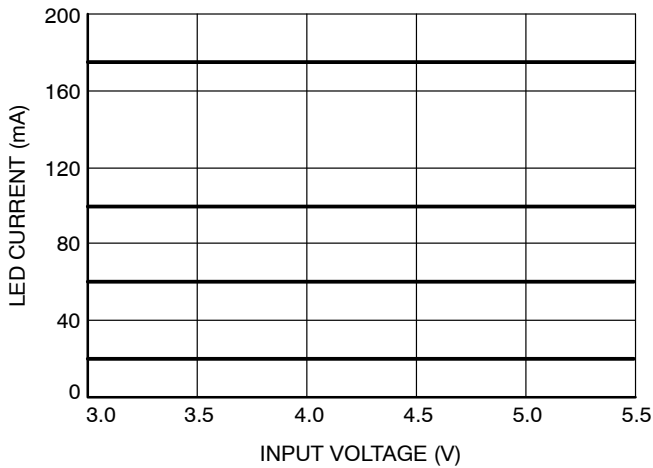


Figure 7. LED Current Change vs. Input Voltage

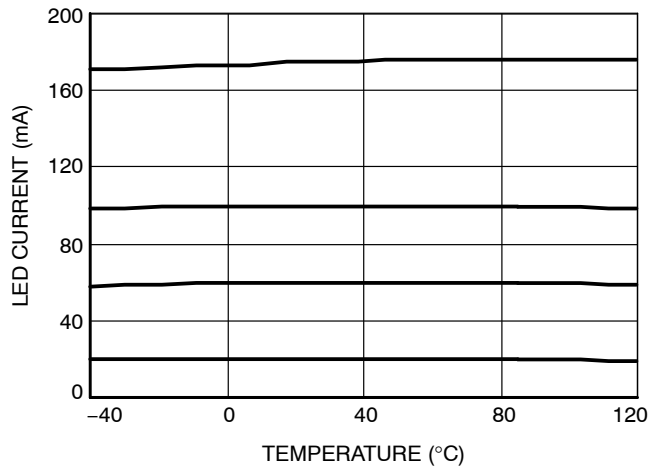


Figure 8. LED Current Change vs. Temperature

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TYPICAL PERFORMANCE CHARACTERISTICS

($V_{IN} = 5\text{ V}$, $V_{DD} = 5\text{ V}$, $C1 = 1\ \mu\text{F}$, $T_{AMB} = 25^\circ\text{C}$ unless otherwise specified.)

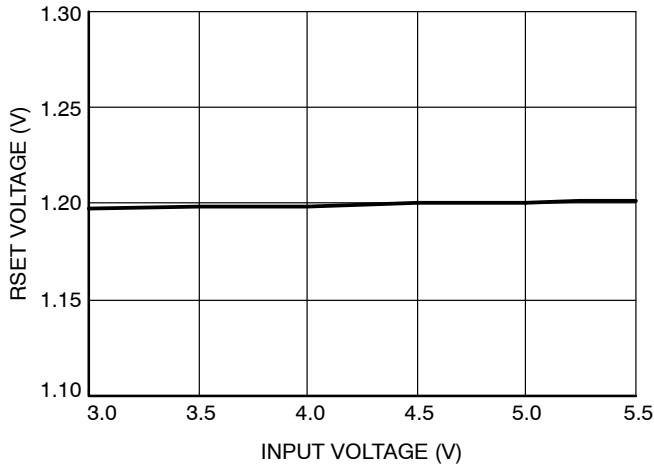


Figure 9. RSET Pin Voltage vs. Input Voltage

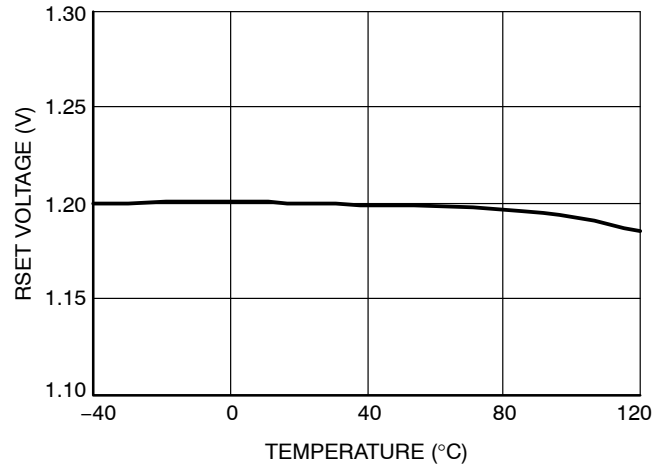


Figure 10. RSET Pin Voltage vs. Temperature

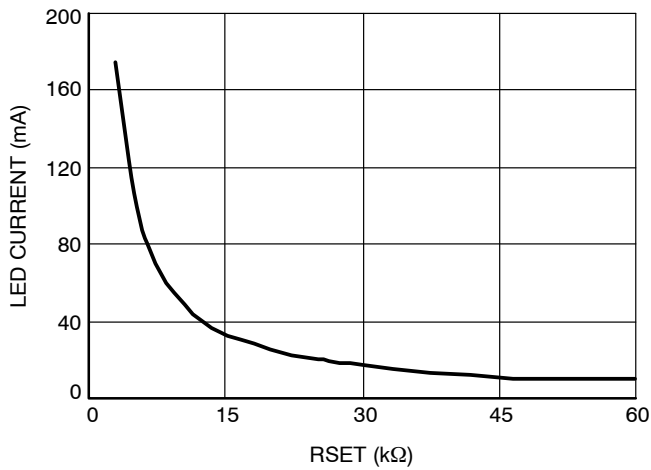


Figure 11. LED Current vs. RSET Resistor

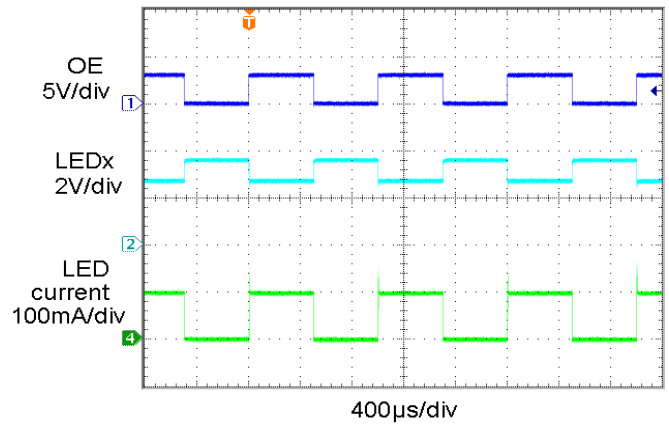


Figure 12. OE Transient Response at 1 kHz

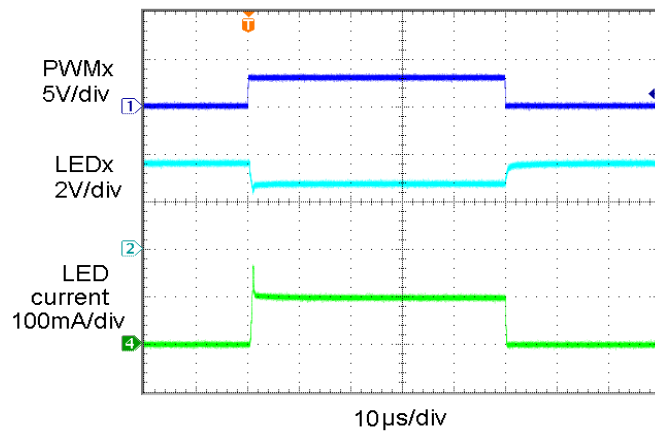


Figure 13. PWMx Transient Response

Table 5. PIN DESCRIPTIONS

| Name | Pin Number | Function |
|-------|------------|--------------------------------|
| PGND | 1 | Power Ground. |
| GND | 2 | Ground Reference. |
| PWM3 | 3 | PWM control input for LED3 |
| PWM2 | 4 | PWM control input for LED2 |
| PWM1 | 5 | PWM control input for LED1 |
| RSET3 | 6 | LED current set pin for LED3 |
| RSET2 | 7 | LED current set pin for LED2 |
| RSET1 | 8 | LED current set pin for LED1 |
| LED3 | 9 | LED channel 3 cathode terminal |
| LED2 | 10 | LED channel 2 cathode terminal |
| LED1 | 11 | LED channel 1 cathode terminal |
| NC | 12 | Not connected inside package |
| NC | 13 | Not connected inside package |
| NC | 14 | Not connected inside package |
| OE | 15 | Output Enable input pin |
| VDD | 16 | Device Supply pin |

Pin Function

PGND is the power ground reference pin for the device. This pin must be connected to the GND pin and to the ground plane on the PCB.

GND is the ground reference pin for the entire device. This pin must be connected to the ground plane on the PCB.

PWM1 to **PWM3** are the control inputs respectively for LED1, LED2 and LED3 channels. When PWMx are low, the associated LED channels are turned off. When PWMx are high, the corresponding channels are turned on, assuming the OE input is also high. PWMx pins can not be left open and must be set either to logic high or low.

RSET1 to **RSET3** are the LED current set inputs. The current pulled out of these pins will be mirrored in the corresponding LED channel with a gain of 400.

LED1 to **LED3** are the LED current sink inputs. These pins are connected to the bottom cathodes of the LED strings.

The current sinks bias the LEDs with a current equal to 400 times the corresponding RSETx pin current. For the LED sink to operate correctly the voltage on the LED pin must be above 0.4 V. Each LED channel can withstand voltages up to 25 V.

OE is the output enable input. When high, all LED channels are enabled according to the state of their corresponding PWMx control inputs. When low, all LED channels are turned off. This pin can be used to turn all the LEDs off independently of the state of the PWMx inputs. If the OE stays low for a duration longer than t_{PWRDWN} , the device enters shutdown mode.

VDD is the positive supply pin voltage for the entire device. A small 1 μ F bypass ceramic capacitor is recommended between VDD pin and ground near the device.

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BLOCK Diagram

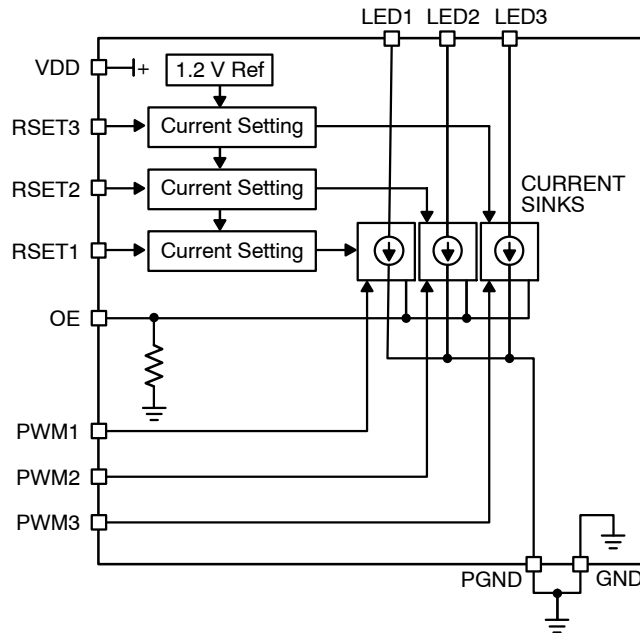


Figure 14. CAT4109 Functional Block Diagram

Basic Operation

The CAT4109 uses 3 independent current sinks to accurately regulate the current in each LED channel to 400 times the current sink from the corresponding RSET pin. Each of the resistors tied to the RSET1, RSET2, RSET3 pins set the current respectively in the LED1, LED2, and LED3 channels. Table 6 shows standard resistor values for RSET and the corresponding LED current.

Table 6. RSET RESISTOR SETTINGS

| LED Current [mA] | RSET [kΩ] |
|------------------|-----------|
| 20 | 24.9 |
| 60 | 8.45 |
| 100 | 5.23 |
| 175 | 3.01 |

Tight current regulation for all channels is possible over a wide range of input and LED voltages due to independent current sensing circuitry on each channel. The LED channels have a low dropout of 0.4 V or less for all current ranges and supply voltages. This helps improve heat dissipation and efficiency.

Upon power-up, an under-voltage lockout circuit sets all outputs off. Once the VDD supply voltage is greater than the under-voltage lockout threshold, the device channel can be turned on. The on/off state of each channel LED1, LED2 and LED3 is independently controlled respectively by PWM1, PWM2, PWM3. When a PWMx is high, the associated LEDx channel is turned on.

Application Information

Power Dissipation

The power dissipation (P_D) of the CAT4109 can be calculated as follows:

$$P_D = (V_{DD} \times I_{DD}) + \sum(V_{LEDN} \times I_{LEDN})$$

where V_{LEDN} is the voltage at the LED pin, and I_{LEDN} is the associated LED current. Combinations of high V_{LED} voltage or high ambient temperature can cause the CAT4109 to enter thermal shutdown. In applications where V_{LEDN} is high, a resistor can be inserted in series with the LED string to lower P_D .

Thermal dissipation of the junction heat consists primarily of two paths in series. The first path is the junction to the case (θ_{JC}) thermal resistance which is defined by the package style, and the second path is the case to ambient (θ_{CA}) thermal resistance, which is dependent on board layout. The overall junction to ambient (θ_{JA}) thermal resistance is equal to:

$$\theta_{JA} = \theta_{JC} + \theta_{CA}$$

For a given package style and board layout, the operating junction temperature T_J is a function of the power dissipation P_D , and the ambient temperature, resulting in the following equation:

$$T_J = T_{AMB} + P_D (\theta_{JC} + \theta_{CA}) = T_{AMB} + P_D \theta_{JA}$$

When mounted on a double-sided printed circuit board with two square inches of copper allocated for “heat spreading”, the resulting θ_{JA} is about 74°C/W.

For example, at 60°C ambient temperature, the maximum power dissipation is calculated as follow:

$$P_{Dmax} = \frac{(T_{Jmax} - T_{AMB})}{\theta_{JA}} = \frac{(150 - 60)}{74} = 1.2 \text{ W}$$

Recommended Layout

Bypass capacitor C1 should be placed as close to the IC as possible. RSET resistors should be directly connected to the GND pin of the device. For better thermal dissipation, multiple via can be used to connect the GND pad to a large ground plane. It is also recommended to use large pads and traces on the PCB wherever possible to spread out the heat. The LEDs for this layout are driven from a separate supply (V_{LED+}), but they can also be driven from the same supply connected to VDD.

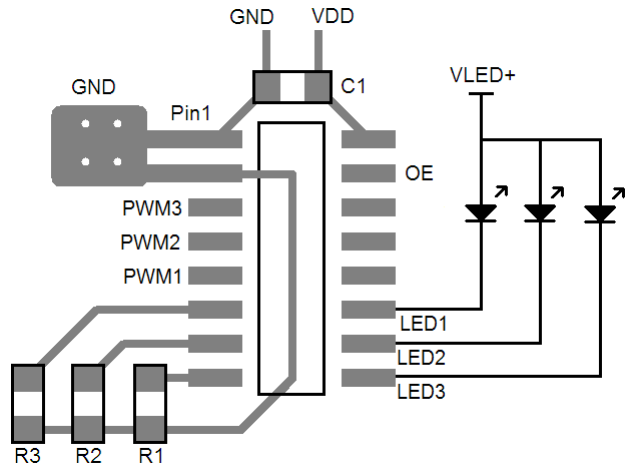
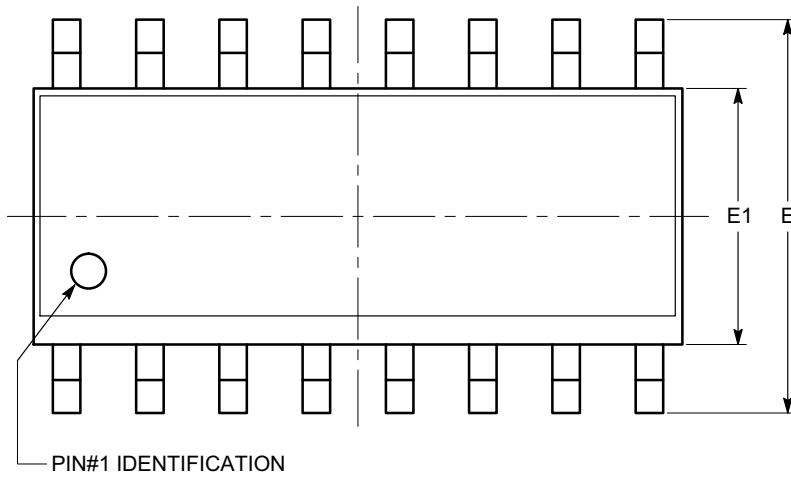


Figure 15. Recommended Layout

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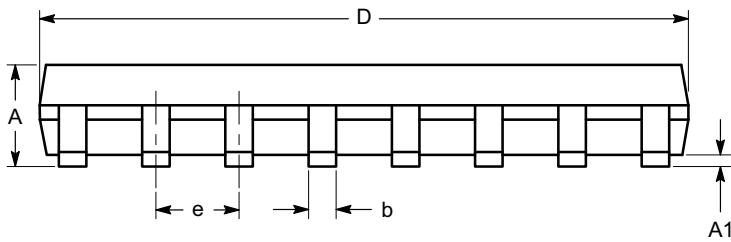
PACKAGE DIMENSIONS

SOIC-16, 150 mils
CASE 751BG-01
ISSUE O

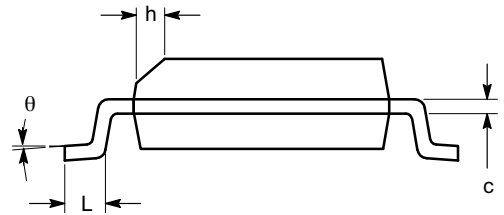


| SYMBOL | MIN | NOM | MAX |
|----------|----------|------|-------|
| A | 1.35 | | 1.75 |
| A1 | 0.10 | | 0.25 |
| b | 0.33 | | 0.51 |
| c | 0.19 | | 0.25 |
| D | 9.80 | 9.90 | 10.00 |
| E | 5.80 | 6.00 | 6.20 |
| E1 | 3.80 | 3.90 | 4.00 |
| e | 1.27 BSC | | |
| h | 0.25 | | 0.50 |
| L | 0.40 | | 1.27 |
| θ | 0° | | 8° |

TOP VIEW



SIDE VIEW



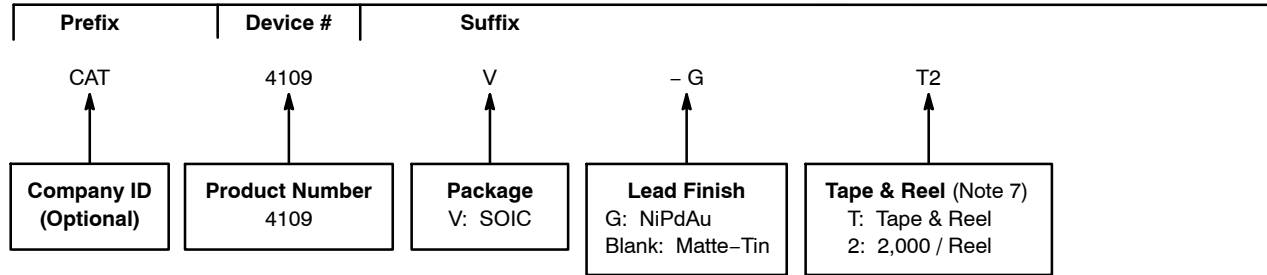
END VIEW

Notes:


- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-012.

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Example of Ordering Information (Note 5)



3. All packages are RoHS-compliant (Lead-free, Halogen-free).
4. The standard plated finish is NiPdAu.
5. The device used in the above example is a CAT4109V-GT2 (SOIC, NiPdAu, Tape & Reel, 2,000/Reel).
6. For additional temperature options, please contact your nearest ON Semiconductor Sales office.
7. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru